



Features:

- Glass passivated chip junction
- High efficiency, low V_F
- High current capability
- High reliability
- High surge current capability
- For use in low voltage, high frequency inverter, free wheeling, and polarity protection application

Specifications:

Mechanical Data:

Cases	: Moulded plastic DO-15
Lead	: Pure tin plated, lead free, solderable per MIL-STD-202, Method 208 guaranteed
Polarity	: Colour band denotes cathode end
High temperature soldering guaranteed	: 260°C/10 seconds/0.375", (9.5mm) lead lengths at 5lbs., (2.3kg) tension
Mounting position	: Any
Weight	: 0.4g

Maximum Ratings and Electrical Characteristics:

Rating at 25°C ambient temperature unless otherwise specified.

Single phase, half wave, 60Hz, resistive or inductive load.

For capacitive load, derate current by 20%.

Type Number	Symbol	HER153G	HER156G	HER158G	Units
Maximum Recurrent Peak Reverse Voltage	V _{RRM}	200	600	1,000	V
Maximum RMS Voltage	V _{RMS}	140	420	700	
Maximum DC Blocking Voltage	V _{DC}	200	600	1,000	
Maximum Average Forward Rectified Current 0.375" (9.5mm) Lead Length at T _A = 55°C	I _(AV)	1.5			A
Peak Forward Surge Current, 8.3ms Single Half Sine-wave Superimposed on Rated Load (JEDEC method)	I _{FSM}	50			
Maximum Instantaneous Forward Voltage at 1.5A	V _F	1	1.7		V

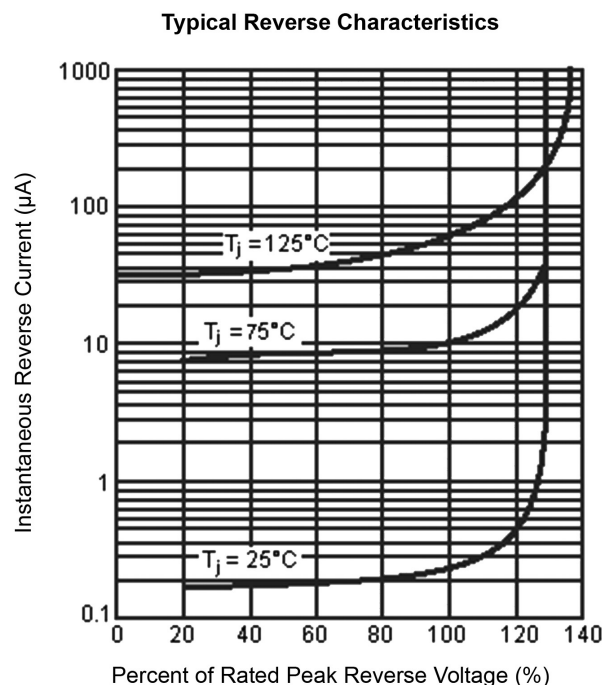
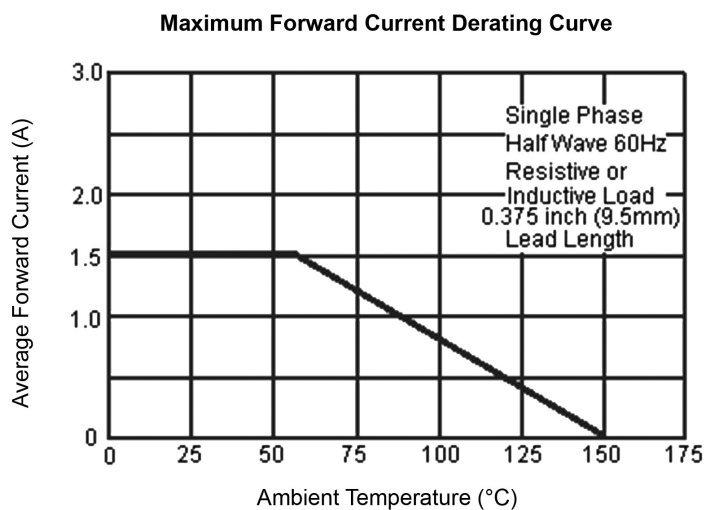
Type Number	Symbol	HER153G	HER156G	HER158G	Units
Maximum DC Reverse Current at T _A = 25°C at Rated DC Blocking Voltage at T _A = 125°C	I _R	5 150			μA μA
Maximum Reverse Recovery Time (Note 1)	T _{rr}	50	75		nS
Typical Junction Capacitance (Note 2)	C _j	50	20		pF
Typical Thermal Resistance	R _{θJA}	60			°C/W
Operating Temperature Range	T _J	-65 to +150			°C
Storage Temperature Range	T _{STG}				

Note: 1. Reverse Recovery Test Conditions: $I_F = 0.5\text{A}$, $I_R = 1\text{A}$, $I_{RR} = 0.25\text{A}$.

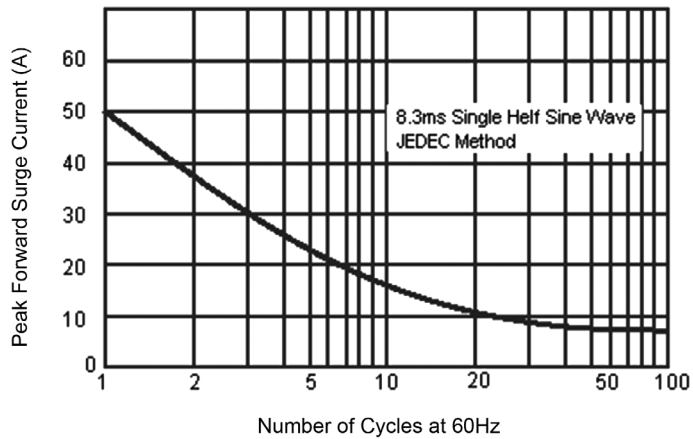
Note: 2. Measured at 1MHz and Applied Reverse Voltage of 4V DC.

Note: 3. Mount on Cu-Pad Size 5mm x 5mm on PCB.

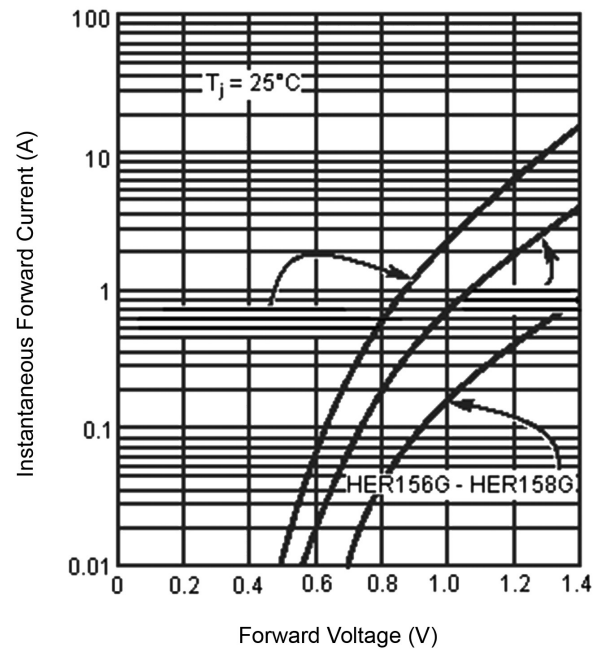
Ratings and Characteristic Curves (HER153G, HER156G, HER158G)



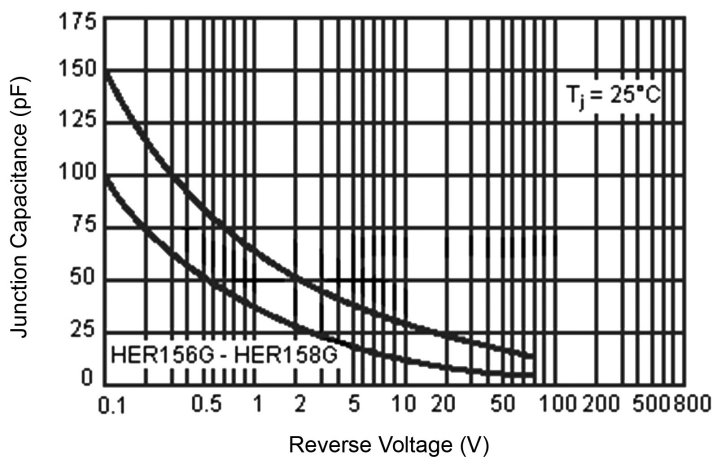
Maximum Non-Repetitive Forward Surge Current



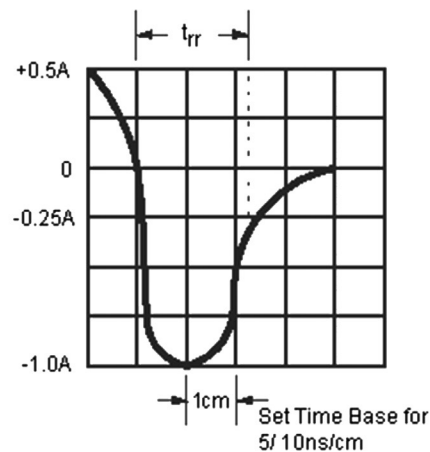
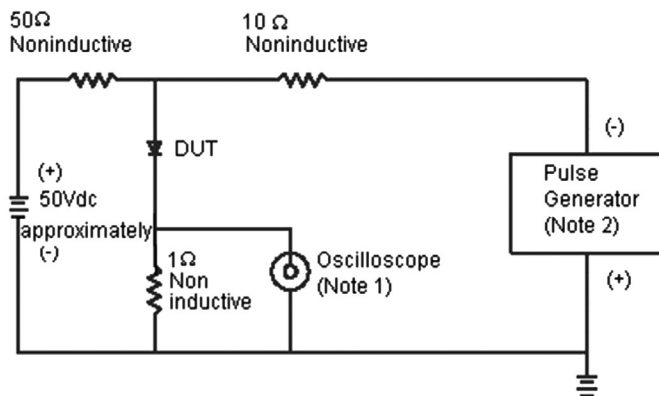
Typical Instantaneous Forward Characteristics



Typical Junction Capacitance



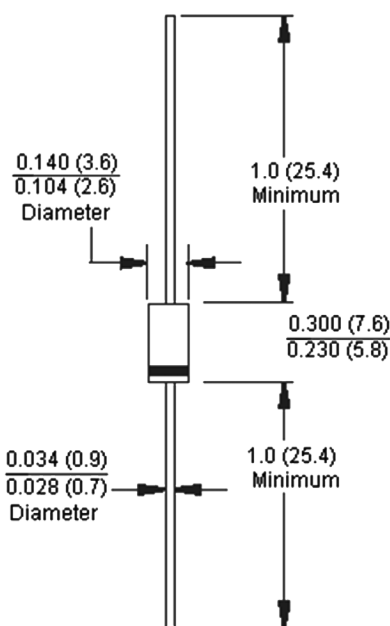
Reverse Recovery Time Characteristic and Test Circuit Diagram



Note: 1. Rise Time = 7ns Maximum. Input Impedance = 1MΩ 22pf

Note: 2. Rise Time = 10ns Maximum Source Impedance = 50Ω

DO-15



Dimensions : Inches (Millimetres)

Part Number Table

Description	Part Number
Diode, Fast, 1.5A, 200V	HER153G
Diode, Fast, 1.5A, 600V	HER156G
Diode, Fast, 1.5A, 1,000V	HER158G

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